



# SGM80581/SGM80582/SGM80584 220MHz, Rail-to-Rail I/O, CMOS Operational Amplifiers

## GENERAL DESCRIPTION

The SGM80581 (single), SGM80582 (dual) and SGM80584 (quad) are high-speed, voltage-feedback CMOS operational amplifiers. They are designed for video and other applications which require wide bandwidth. They are unity-gain stable and can provide large output current. Differential gain is 0.01% and differential phase is 0.1°. Quiescent current is only 4.5mA/Amplifier.

The SGM80581/2/4 are optimized for operation on single or dual supplies as low as 2.5V ( $\pm 1.25V$ ) and up to 5.5V ( $\pm 2.75V$ ). Input common mode range extends beyond the supplies. The output swing is within 15mV of the rails, supporting wide dynamic range.

The SGM80581/2/4 are suitable for applications requiring high continuous output current. Multichannel versions feature completely independent circuitry for lowest crosstalk and freedom from interaction.

The single SGM80581 is available in Green SOT-23-5 and SOIC-8 packages. The dual SGM80582 is available in Green MSOP-8 and SOIC-8 packages. The quad SGM80584 is available in a Green SOIC-14 package. All are specified over the extended -40°C to +125°C temperature range.

## FEATURES

- **Unity-Gain Bandwidth: 220MHz**
- **Wide Bandwidth: 100MHz GBP**
- **High Slew Rate: 160V/ $\mu$ s**
- **Low Noise: 7nV/ $\sqrt{Hz}$  at 1MHz**
- **Rail-to-Rail Input and Output**
- **High Output Current: 150mA (TYP)**
- **Excellent Video Performance:**
  - **Diff Gain: 0.01%, Diff Phase: 0.1°**
  - **0.1dB Gain Flatness: 30MHz**
- **Low Input Bias Current: 2pA**
- **Quiescent Current: 4.5mA/Amplifier (TYP)**
- **Thermal Shutdown**
- **2.5V to 5.5V Single Supply or  $\pm 1.25V$  to  $\pm 2.75V$  Dual Power Supplies**
- **-40°C to +125°C Operating Temperature Range**
- **Small Packaging:**
  - **SGM80581 Available in Green SOT-23-5 and SOIC-8 Packages**
  - **SGM80582 Available in Green MSOP-8 and SOIC-8 Packages**
  - **SGM80584 Available in a Green SOIC-14 Package**

## APPLICATIONS

Video Processings  
Ultrasound  
Optical Networking, Tunable Lasers  
Photodiode Transimpedance Amplifiers  
Active Filters  
High-Speed Integrators  
Analog-to-Digital (A/D) Converter Input Buffers  
Digital-to-Analog (D/A) Converter Output Amplifiers  
Barcode Scanners

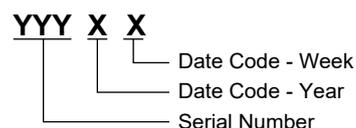
**PACKAGE/ORDERING INFORMATION**

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM80581	SOT-23-5	-40°C to +125°C	SGM80581XN5G/TR	SU1XX	Tape and Reel, 3000
	SOIC-8	-40°C to +125°C	SGM80581XS8G/TR	SGM 80581XS8 XXXXX	Tape and Reel, 2500
SGM80582	MSOP-8	-40°C to +125°C	SGM80582XMS8G/TR	SGM80582 XMS8 XXXXX	Tape and Reel, 4000
	SOIC-8	-40°C to +125°C	SGM80582XS8G/TR	SGM 80582XS8 XXXXX	Tape and Reel, 2500
SGM80584	SOIC-14	-40°C to +125°C	SGM80584XS14G/TR	SGM80584XS14 XXXXX	Tape and Reel, 2500

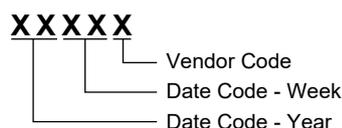
**MARKING INFORMATION**

NOTE: XX = Date Code. XXXXX = Date Code and Vendor Code.

**SOT-23-5**



**SOIC-8/MSOP-8/SOIC-14**



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

**ABSOLUTE MAXIMUM RATINGS**

- Supply Voltage, +V<sub>S</sub> to -V<sub>S</sub> .....6V
- Input Common Mode Voltage Range  
..... (-V<sub>S</sub>) - 0.1V to (+V<sub>S</sub>) + 0.1V
- Signal Input Terminals Voltage Range  
..... (-V<sub>S</sub>) - 0.3V to (+V<sub>S</sub>) + 0.3V
- Output Short-Circuit..... Continuous
- Junction Temperature.....+150°C
- Storage Temperature Range .....-65°C to +150°C
- Lead Temperature (Soldering, 10s).....+260°C
- ESD Susceptibility
- HBM..... 6000V
- MM.....400V
- CDM ..... 1000V

**RECOMMENDED OPERATING CONDITIONS**

- Specified Voltage Range .....2.7V to 5.5V
- Operating Temperature Range .....-40°C to +125°C

**OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

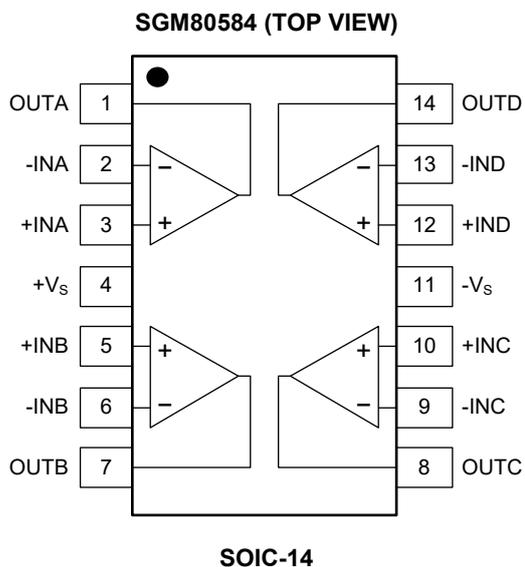
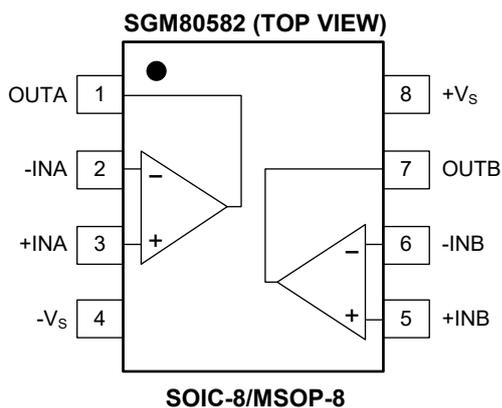
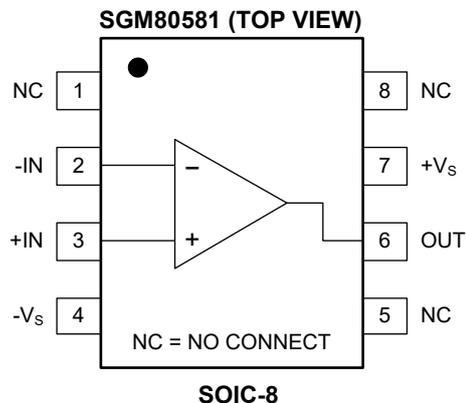
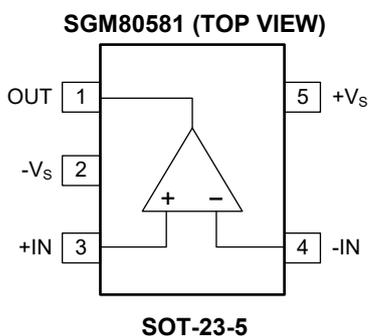
**ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

**PIN CONFIGURATIONS**



**ELECTRICAL CHARACTERISTICS**

(At  $T_A = +25^\circ\text{C}$ ,  $V_S = 2.7\text{V}$  to  $5.5\text{V}$ ,  $V_{CM} = V_S/2$ ,  $V_{OUT} = V_S/2$ ,  $R_L = 1\text{k}\Omega$  connected to  $V_S/2$ , unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>Input Characteristics</b>					
Input Offset Voltage ( $V_{OS}$ )	$V_S = 5\text{V}$		1.0	3.0	mV
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			6.5	
Input Offset Voltage Drift ( $\Delta V_{OS}/\Delta T$ )	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		6.5		$\mu\text{V}/^\circ\text{C}$
Input Bias Current ( $I_B$ )			2		pA
Input Offset Voltage ( $I_{OS}$ )			0.1		pA
Input Common Mode Voltage Range ( $V_{CM}$ )		$(-V_S) - 0.1$		$(+V_S) + 0.1$	V
Common Mode Rejection Ratio (CMRR)	$V_S = 5.5\text{V}$ , $-0.1\text{V} < V_{CM} < 5.6\text{V}$	56	71		dB
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	53			
	$V_S = 5.5\text{V}$ , $-0.1\text{V} < V_{CM} < 3.5\text{V}$	60	71		
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	58			
Open-Loop Voltage Gain ( $A_{OL}$ )	$(-V_S) + 0.3\text{V} < V_{OUT} < (+V_S) - 0.3\text{V}$ , $R_L = 1\text{k}\Omega$	89	109		dB
	$(-V_S) + 0.4\text{V} < V_{OUT} < (+V_S) - 0.4\text{V}$ , $R_L = 1\text{k}\Omega$	89	109		
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	84			
<b>Input Impedance</b>					
Differential			$10^{12} \parallel 4$		$\Omega \parallel \text{pF}$
Common Mode			$10^{12} \parallel 6$		$\Omega \parallel \text{pF}$
<b>Output Characteristics</b>					
Output Voltage Swing from Rail	$V_S = 5\text{V}$ , $R_L = 1\text{k}\Omega$		15	62	mV
Short-Circuit Current ( $I_{SC}$ )	$V_S = 5\text{V}$	110	150		mA
	$V_S = 3\text{V}$		90		
Closed-Loop Output Impedance	$f < 100\text{kHz}$		0.1		$\Omega$
<b>Dynamic Performance</b>					
-3dB Small-Signal Bandwidth ( $f_{3dB}$ )	$G = +1$ , $V_{OUT} = 100\text{mV}_{PP}$ , $R_F = 25\Omega$		220		MHz
	$G = +2$ , $V_{OUT} = 100\text{mV}_{PP}$		106		
Gain-Bandwidth Product (GBP)	$G = +10$ , $V_{OUT} = 100\text{mV}_{PP}$		100		MHz
Bandwidth for 0.1dB Gain Flatness	$G = +2$ , $V_{OUT} = 100\text{mV}_{PP}$		30		MHz
Slew Rate (SR)	$V_S = 5\text{V}$ , $V_{OUT} = 2V_{PP}$		160		V/ $\mu\text{s}$
	$V_S = 5\text{V}$ , $V_{OUT} = 4V_{PP}$		170		
Rise-and-Fall Time	$G = +1$ , $V_{OUT} = 200\text{mV}_{PP}$ , 10% to 90%		3.5		ns
	$G = +1$ , $V_{OUT} = 2V_{PP}$ , 10% to 90%		12		
Settling Time to 0.1%	$V_{OUT} = 2V_{PP}$		75		ns
	$V_{OUT} = 4V_{PP}$		35		
Overload Recovery Time	$V_{IN} \times G = V_S$		18		ns
Crosstalk (SGM80582/4)	$f = 5\text{MHz}$		-110		dB

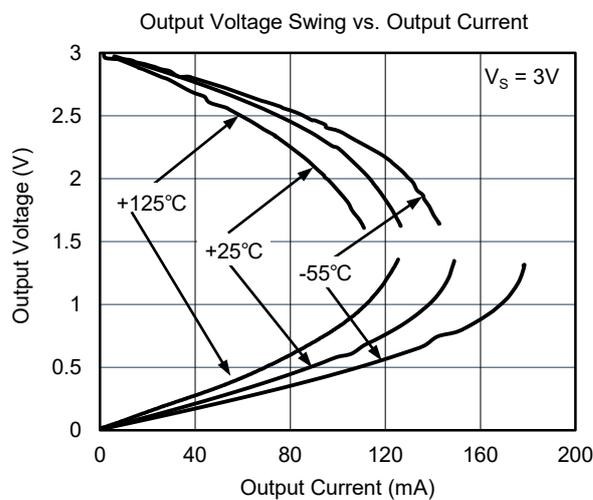
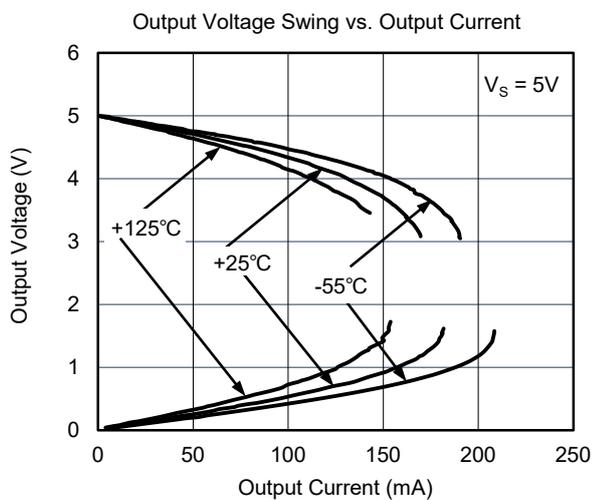
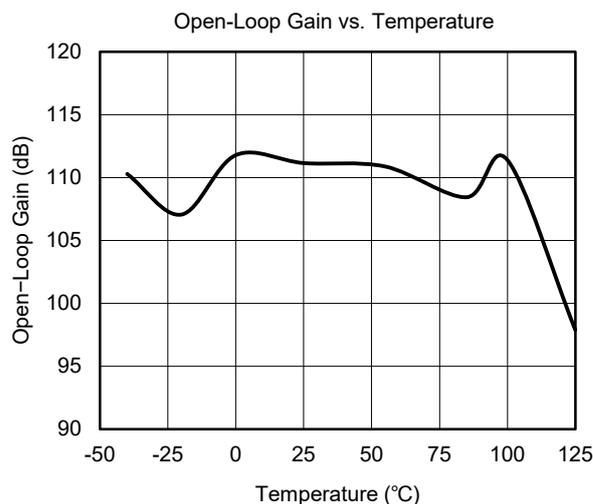
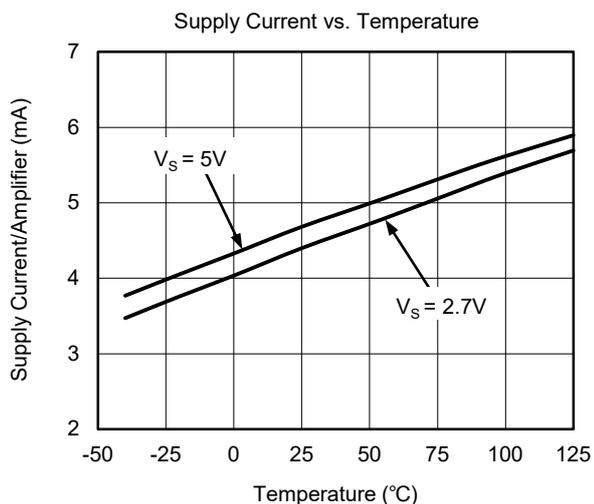
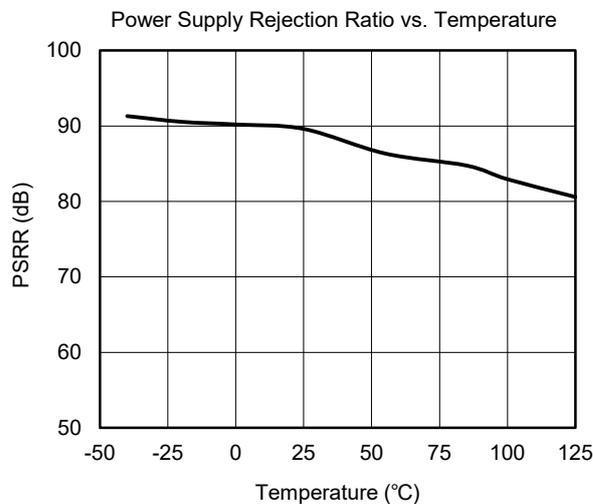
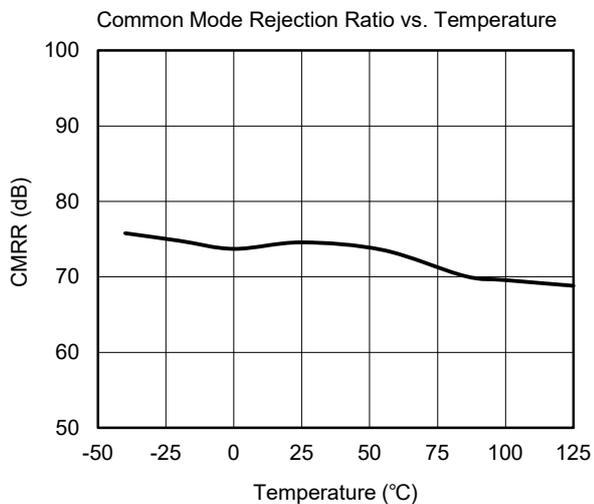
**ELECTRICAL CHARACTERISTICS (continued)**

(At  $T_A = +25^\circ\text{C}$ ,  $V_S = 2.7\text{V}$  to  $5\text{V}$ ,  $V_{CM} = V_S/2$ ,  $V_{OUT} = V_S/2$ ,  $R_L = 1\text{k}\Omega$  connected to  $V_S/2$ , unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>Power Supply</b>					
Specified Voltage Range ( $V_S$ )		2.7		5.5	V
Operating Voltage Range		2.5		5.5	V
Power Supply Rejection Ratio (PSRR)	$V_S = 2.7\text{V}$ to $5.5\text{V}$ , $V_{CM} = (V_S/2) - 0.55\text{V}$		100	540	$\mu\text{V/V}$
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			620	
Quiescent Current/Amplifier ( $I_Q$ )	$V_S = 5\text{V}$ , $I_{OUT} = 0$		4.5	7	mA
	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			9	
<b>Noise/Distortion Performance</b>					
Input Voltage Noise Density ( $e_n$ )	$f = 1\text{MHz}$		7		$\text{nV}/\sqrt{\text{Hz}}$
Input Current Noise Density ( $i_n$ )	$f = 1\text{MHz}$		10		$\text{fA}/\sqrt{\text{Hz}}$
Differential Gain Error	PAL, $R_L = 150\Omega$		0.01		%
Differential Phase Error	PAL, $R_L = 150\Omega$		0.1		$^\circ$
Harmonic Distortion (2nd-Harmonic)	$G = +1$ , $f = 1\text{MHz}$ , $V_{OUT} = 2V_{PP}$ , $R_L = 200\Omega$ , $V_{CM} = 1.5\text{V}$		-66		$\text{dBc}$
Harmonic Distortion (3rd-Harmonic)	$G = +1$ , $f = 1\text{MHz}$ , $V_{OUT} = 2V_{PP}$ , $R_L = 200\Omega$ , $V_{CM} = 1.5\text{V}$		-76		$\text{dBc}$
<b>Thermal Shutdown</b>					
Thermal Shutdown			150		$^\circ\text{C}$
Reset from Shutdown			130		$^\circ\text{C}$

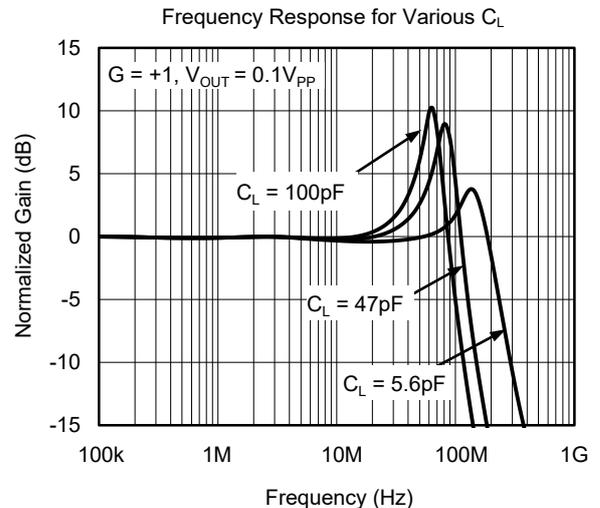
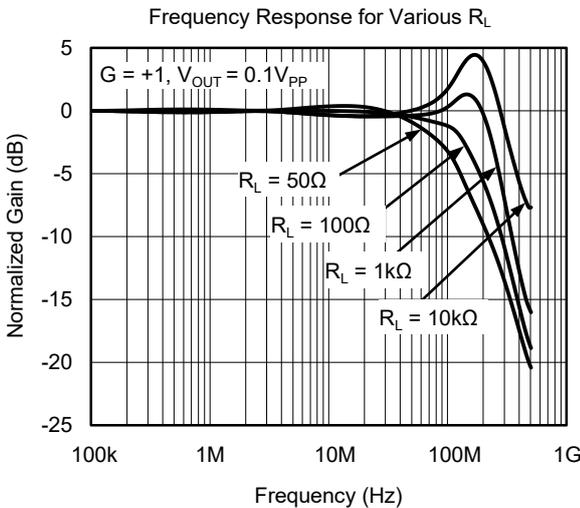
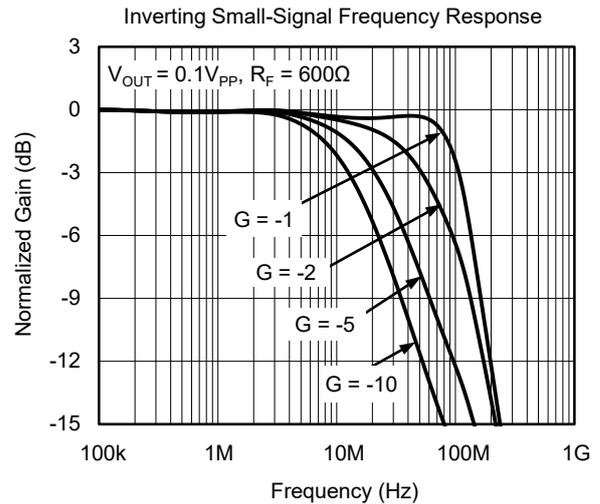
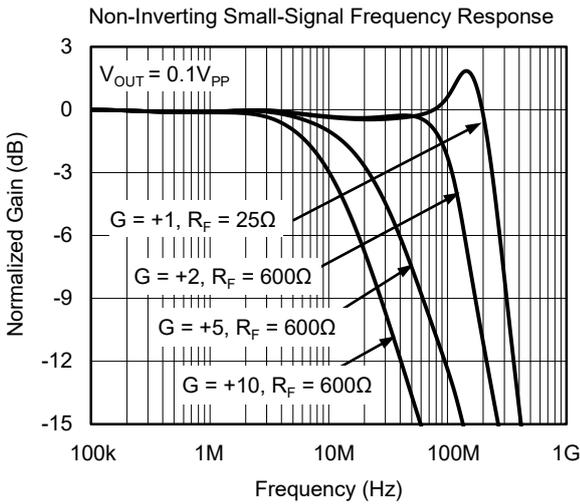
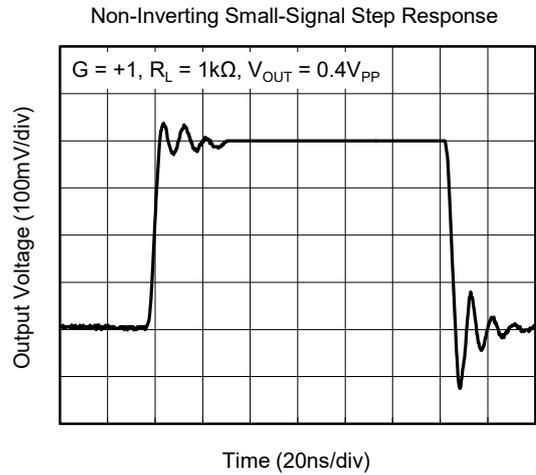
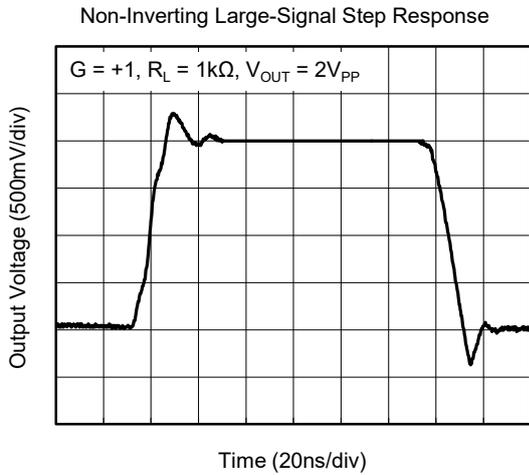
**TYPICAL PERFORMANCE CHARACTERISTICS**

At  $T_A = +25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $G = +1$ ,  $R_L = 1\text{k}\Omega$  and connected to  $V_S/2$ , unless otherwise noted.



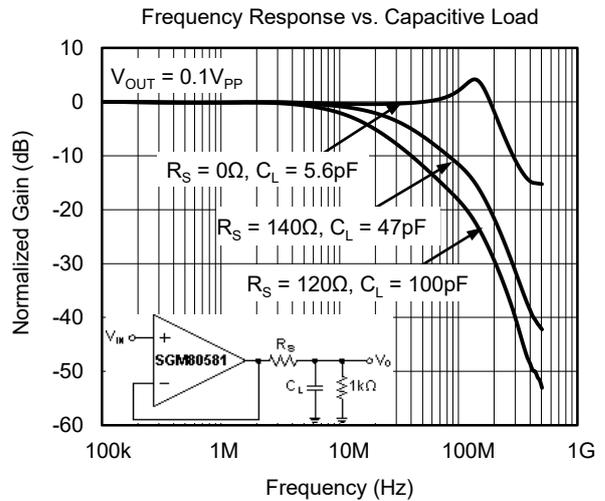
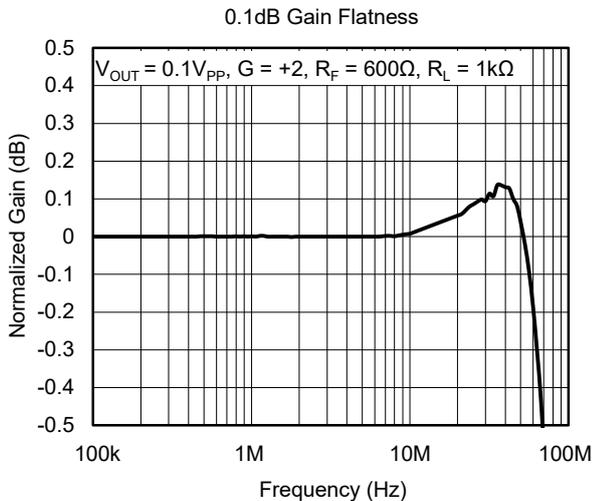
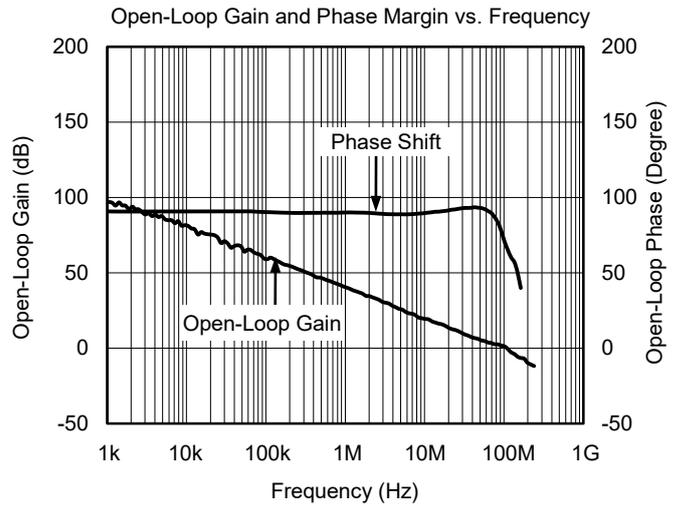
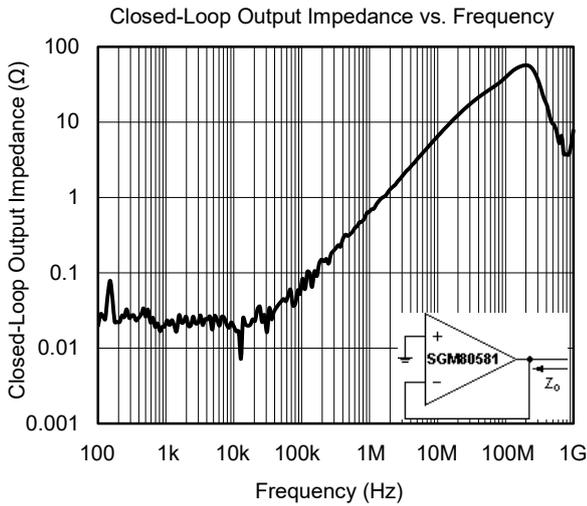
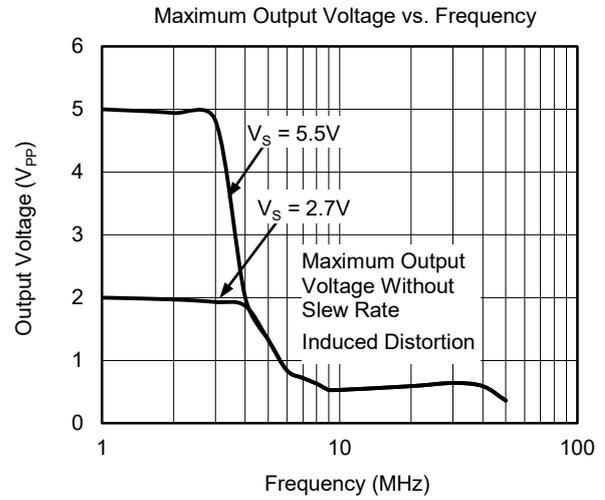
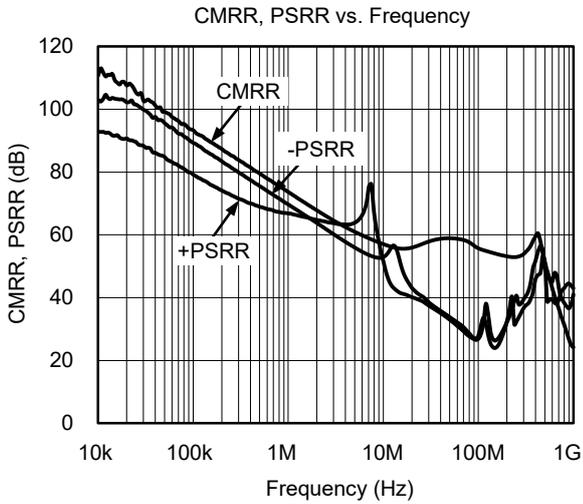
**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $G = +1$ ,  $R_L = 1\text{k}\Omega$  and connected to  $V_S/2$ , unless otherwise noted.



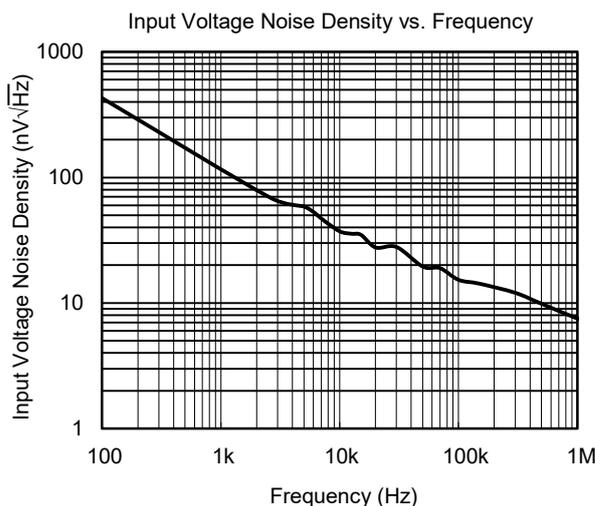
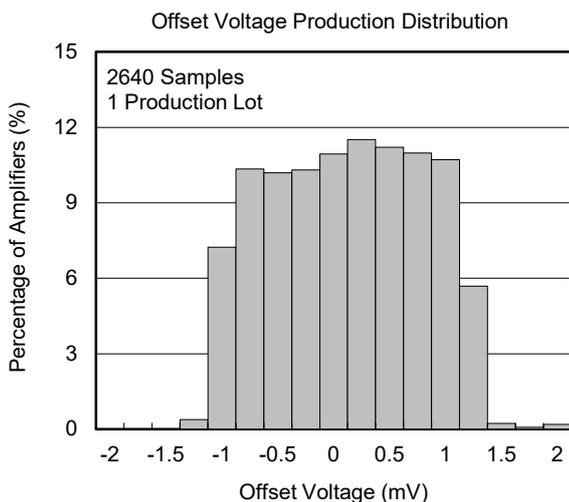
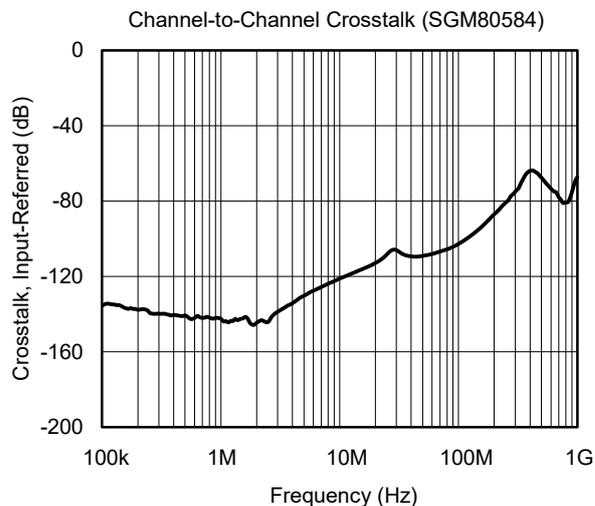
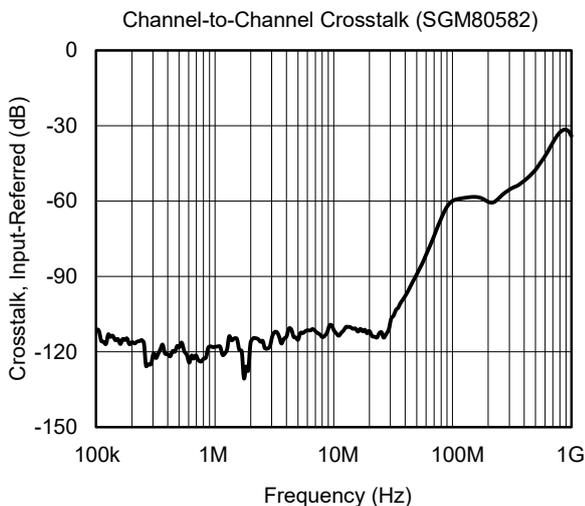
**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $G = +1$ ,  $R_L = 1\text{k}\Omega$  and connected to  $V_S/2$ , unless otherwise noted.



**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $V_S = 5\text{V}$ ,  $G = +1$ ,  $R_L = 1\text{k}\Omega$  and connected to  $V_S/2$ , unless otherwise noted.



**APPLICATION INFORMATION**

The SGM80581/2/4 are CMOS, rail-to-rail I/O, high-speed, voltage-feedback operational amplifiers designed for video, high-speed and other applications. They are available as single, dual or quad operational amplifiers.

The amplifier features a 100MHz gain-bandwidth product, and 160V/ $\mu$ s slew rate. It is unity-gain stable and can be operated as a +1V/V voltage follower.

**Operating Voltage**

The SGM80581/2/4 are specified over a power supply range of 2.7V to 5.5V ( $\pm 1.35$ V to  $\pm 2.75$ V). However, the supply voltage may range from 2.5V to 5.5V ( $\pm 1.25$ V to  $\pm 2.75$ V). Supply voltages higher than 6V (absolute maximum) can permanently damage the amplifier.

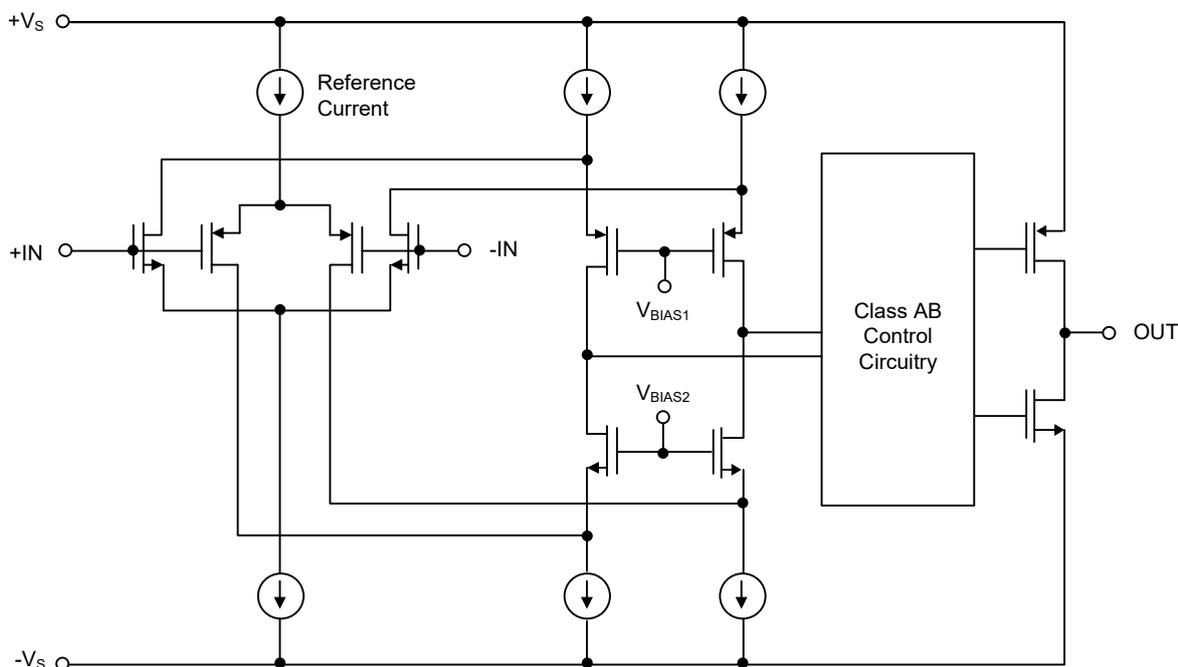
**Rail-to-Rail Output**

A class AB output stage with common-source transistors is used to achieve rail-to-rail output. For high-impedance loads ( $> 1k\Omega$ ), the output voltage swing is typically within 15mV from the supply rails.

**Rail-to-Rail Input**

The specified input common mode voltage range of the SGM80581/2/4 extends 100mV beyond the supply rails. This is achieved with a complementary input stage, an N-channel input differential pair in parallel with a P-channel differential pair, as shown in Figure 1. The N-channel pair is active for input voltages close to the positive rail, typically  $(+V_S) - 1.2$ V to 100mV above the positive supply, while the P-channel pair is on for input voltages from 100mV below the negative supply to approximately  $(+V_S) - 1.2$ V. There is a small transition region, typically  $(+V_S) - 1.5$ V to  $(+V_S) - 0.9$ V, in which both pairs are on. This 600mV transition region can vary  $\pm 500$ mV with process variation. Thus, the transition region (both input stages on) can range from  $(+V_S) - 2.0$ V to  $(+V_S) - 1.5$ V on the low end, up to  $(+V_S) - 0.9$ V to  $(+V_S) - 0.4$ V on the high end.

A folded-cascode adds the signal from the two input pairs and presents a differential signal to the class AB output stage.



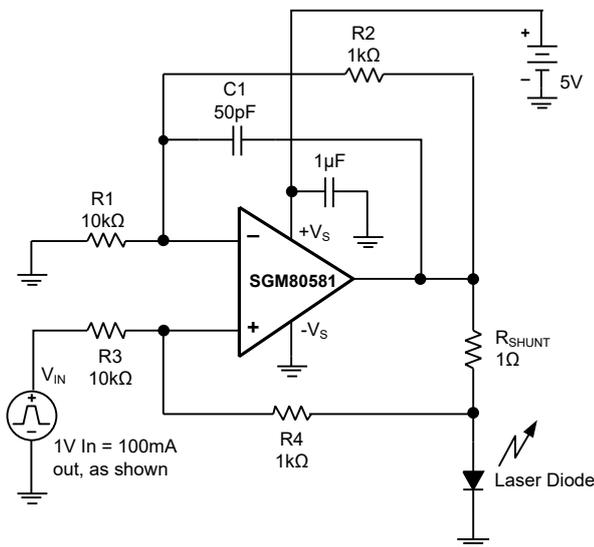
**Figure 1. Simplified Schematic**

**APPLICATION INFORMATION (continued)**

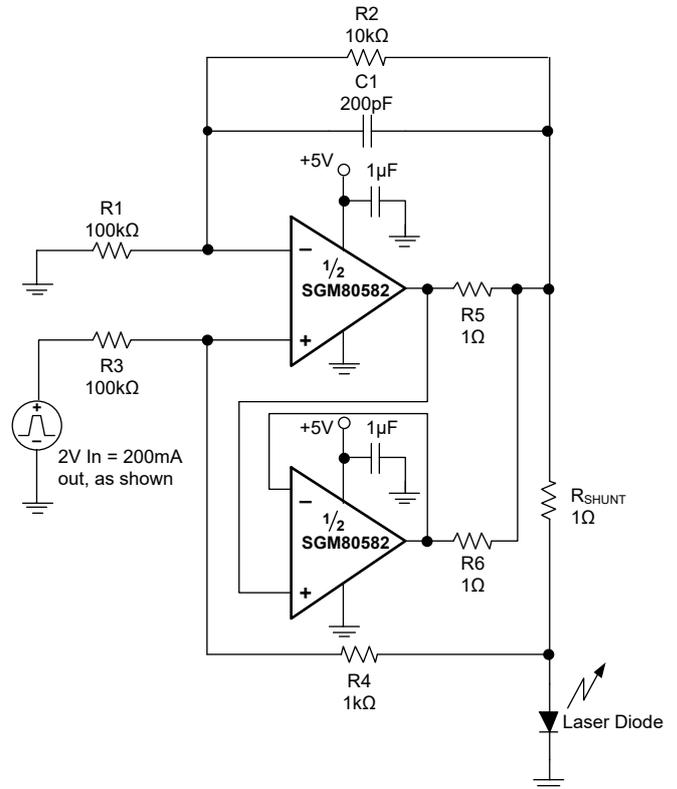
**Output Drive**

The SGM80581's output stage can supply a continuous output current of  $\pm 100\text{mA}$ , as shown in Figure 2. For maximum reliability, it is not recommended to run a continuous DC current in excess of  $\pm 110\text{mA}$ . For supplying continuous output currents greater than  $\pm 110\text{mA}$ , the SGM80581 may be operated in parallel, as shown in Figure 3.

The on-chip thermal shutdown circuit is provided to protect the SGM80581/2/4 from dangerously high junction temperatures. At  $+150^\circ\text{C}$ , the protection circuit will shut down the amplifier. Normal operation will resume when the junction temperature cools to below  $+130^\circ\text{C}$ .



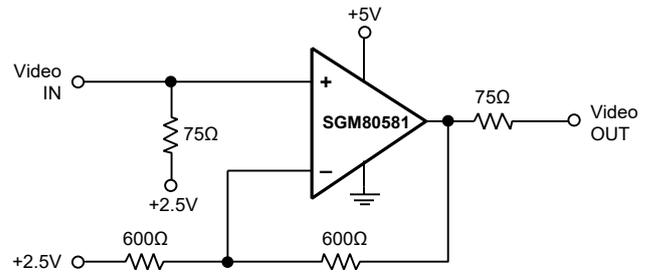
**Figure 2. Laser Diode Driver**



**Figure 3. Parallel Operation**

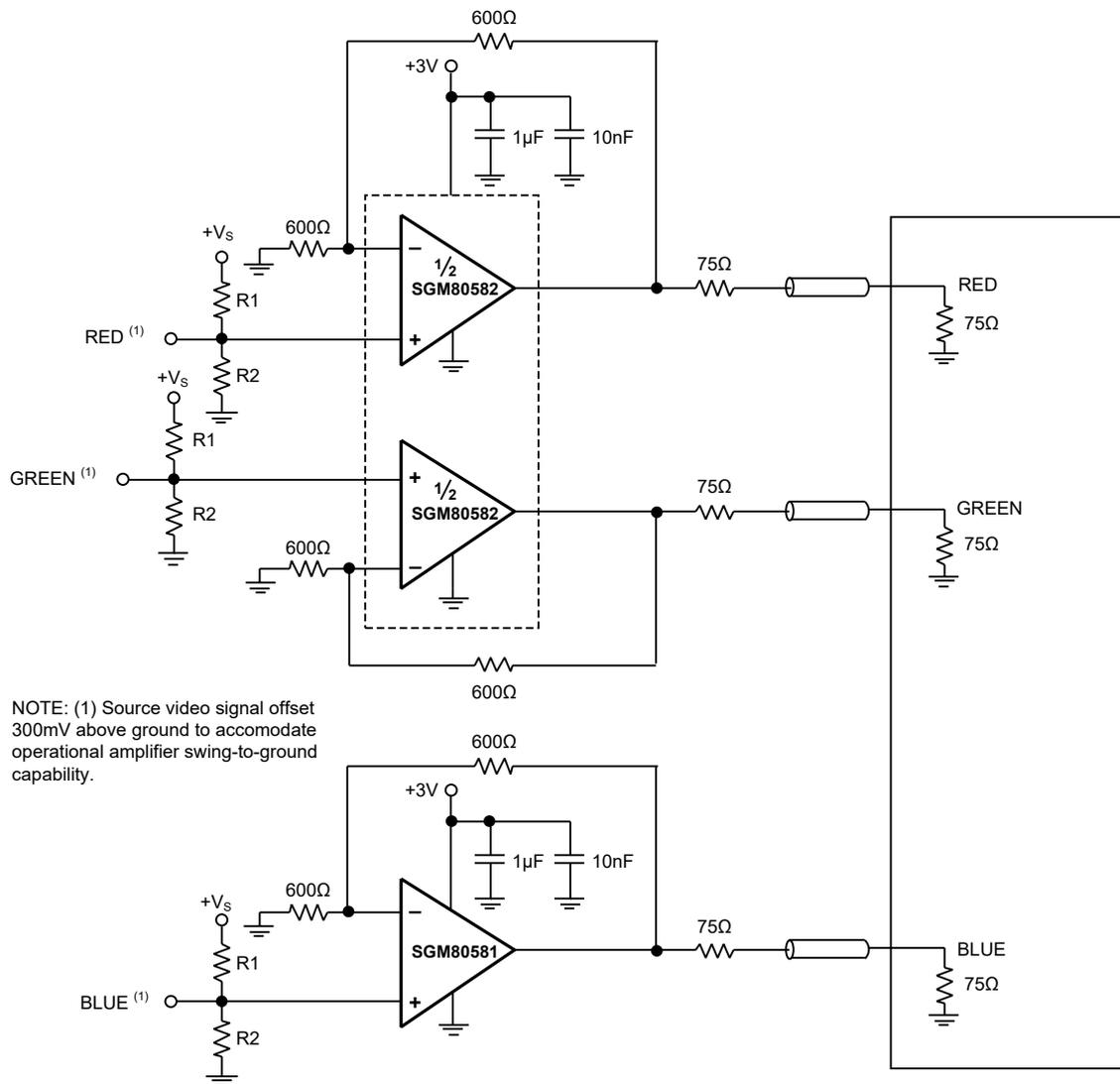
**Video**

The SGM80581 output stage is capable of driving standard back-terminated  $75\Omega$  video cables, as shown in Figure 4. By back-terminating a transmission line, it does not exhibit a capacitive load to its driver. A properly back-terminated  $75\Omega$  video cable does not appear as capacitance; it presents only a  $150\Omega$  resistive load to the SGM80581 output. The SGM80581/2/4 can be used as an amplifier for RGB graphic signals, which have a voltage of zero at the video black level, by offsetting and AC-coupling the signal. See Figure 5.



**Figure 4. Single-Supply Video Line Driver**

**APPLICATION INFORMATION (continued)**



**Figure 5. RGB Cable Driver**

**APPLICATION INFORMATION (continued)**

**Driving Analog-to-Digital Converters**

The SGM80581/2/4 offer 75ns of settling time to 0.1%, making them good choices for driving high- and medium-speed sampling A/D converters and reference circuits. The SGM80581/2/4 provide effective means of buffering the A/D converter’s input capacitance and resulting charge injection while providing signal gain.

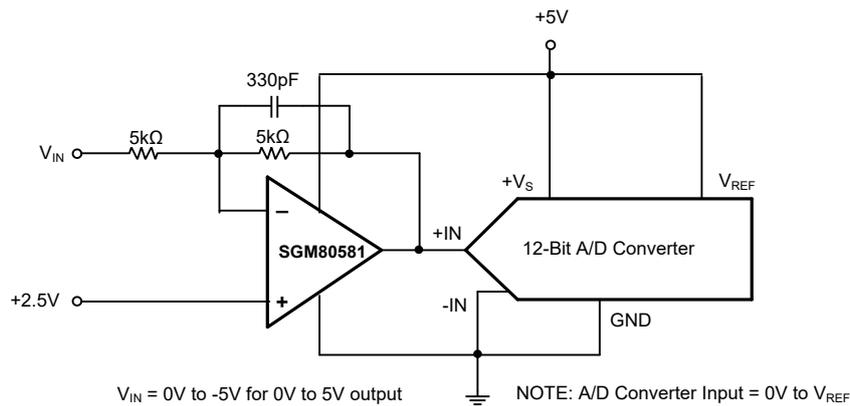
Figure 6 illustrates the SGM80581 driving an A/D converter. With the SGM80581 in an inverting configuration, a capacitor across the feedback resistor can be used to filter high-frequency noise in the signal.

**Capacitive Load and Stability**

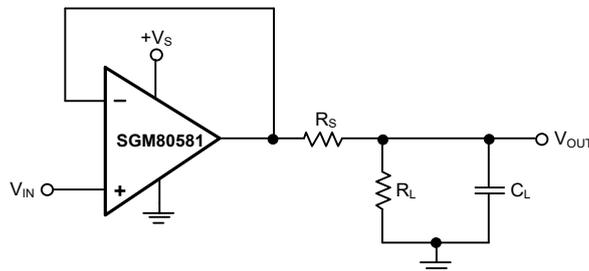
The SGM80581/2/4 can drive a wide range of capacitive loads. However, all operational amplifiers under certain conditions may become unstable. Operational amplifier

configuration, gain and load value are just a few of the factors to consider when determining stability. An operational amplifier in unity-gain configuration is most susceptible to the effects of capacitive loading. The capacitive load reacts with the operational amplifier’s output resistance, along with any additional load resistance, to create a pole in the small-signal response that degrades the phase margin.

One method of improving capacitive load drive in the unity-gain configuration is to insert a resistor in series with the output, as shown in Figure 7. This significantly reduces ringing with large capacitive loads. However, if there is a resistive load in parallel with the capacitive load,  $R_S$  creates a voltage divider. This introduces a DC error at the output and slightly reduces output swing. This error may be insignificant.



**Figure 6. The SGM80581 in Inverting Configuration Driving an ADC**



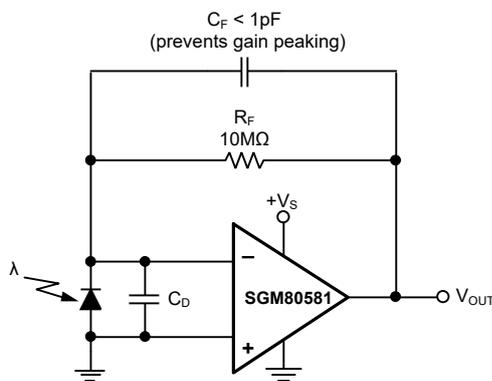
**Figure 7. Series Resistor in Unity-Gain Configuration Improves Capacitive Load Drive**

## APPLICATION INFORMATION (continued)

### Wideband Transimpedance Amplifier

Wide bandwidth, low input bias current, low input voltage and current noise make the SGM80581/2/4 ideal wideband photodiode transimpedance amplifiers for low-voltage single-supply applications. Low-voltage noise is important because photodiode capacitance causes the effective noise gain of the circuit to increase at high frequency.

The key elements to a transimpedance design, as shown in Figure 8, are the expected diode capacitance, the desired transimpedance gain ( $R_F$ ), and the gain-bandwidth product (GBP) of the SGM80581 (100MHz). With these 3 variables set, the feedback capacitor value ( $C_F$ ) may be set to control the frequency response.



**Figure 8. Transimpedance Amplifier**

To achieve a maximally flat 2nd-order Butterworth frequency response, the feedback pole should be set to:

$$\frac{1}{2\pi R_F C_F} = \sqrt{\frac{\text{GBP}}{4\pi R_F C_D}} \quad (1)$$

Typical surface-mount resistors have a parasitic capacitance of around 0.2pF that must be deducted from the calculated feedback capacitance value. Bandwidth is calculated by:

$$f_{-3\text{dB}} = \sqrt{\frac{\text{GBP}}{2\pi R_F C_D}} \text{ Hz} \quad (2)$$

### PCB Layout

Good high-frequency printed circuit board (PCB) layout techniques should be employed for the SGM80581/2/4. Generous use of ground planes, short and direct signal traces, and a suitable bypass capacitor located close to the  $+V_S$  pin will assure clean, stable operation. Large areas of copper also provide a means of dissipating heat that is generated in normal operation.

Sockets are definitely not recommended for use with any high-speed amplifier.

A 10nF ceramic bypass capacitor is the minimum recommended value; adding a 1 $\mu$ F or larger tantalum capacitor in parallel can be beneficial when driving a low-resistance load. Providing adequate bypass capacitance is essential to achieve very low harmonic and intermodulation distortion.

### Power Dissipation

Power dissipation depends on power supply voltage, signal and load conditions. With DC signals, power dissipation is equal to the product of output current times the voltage across the conducting output transistor,  $V_S - V_{\text{OUT}}$ . Power dissipation can be minimized by using the lowest possible power-supply voltage necessary to assure the required output voltage swing.

For resistive loads, the maximum power dissipation occurs at a DC output voltage of one-half the power supply voltage. Dissipation with AC signals is lower.

Any tendency to activate the thermal protection circuit indicates excessive power dissipation or an inadequate heatsink. For reliable operation, junction temperature should be limited to +150°C (maximum). To estimate the margin of safety in a complete design, increase the ambient temperature until the thermal protection is triggered at +150°C. The thermal protection should be triggered at more than +35°C above the maximum expected ambient condition of your application.

## **REVISION HISTORY**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>OCTOBER 2019 – REV.A.1 to REV.A.2</b>	<b>Page</b>
Updated Marking Information section.....	2

---

<b>JUNE 2019 – REV.A to REV.A.1</b>	<b>Page</b>
Updated Electrical Characteristics section.....	4

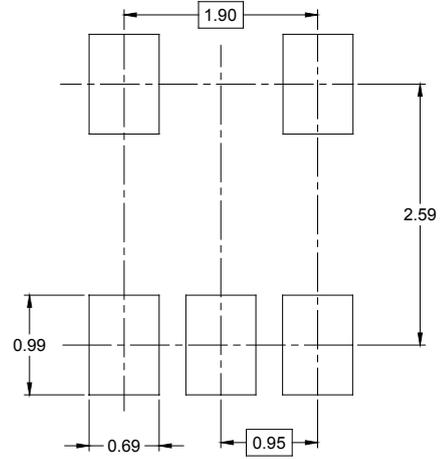
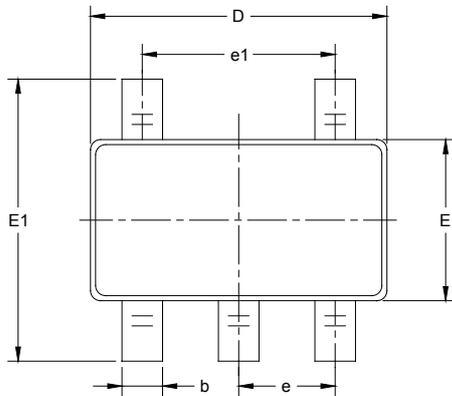
---

<b>Changes from Original (DECEMBER 2016) to REV.A</b>	<b>Page</b>
Changed from product preview to production data.....	All

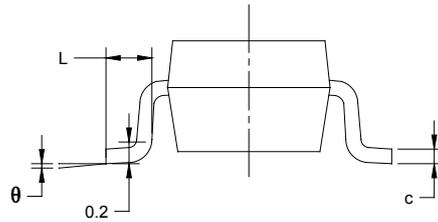
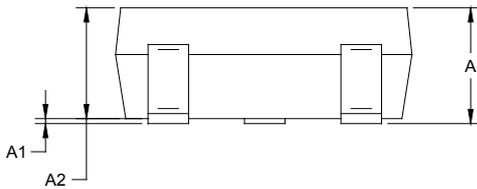
---

PACKAGE OUTLINE DIMENSIONS

SOT-23-5



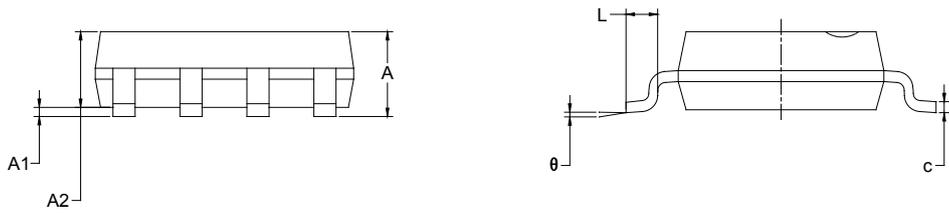
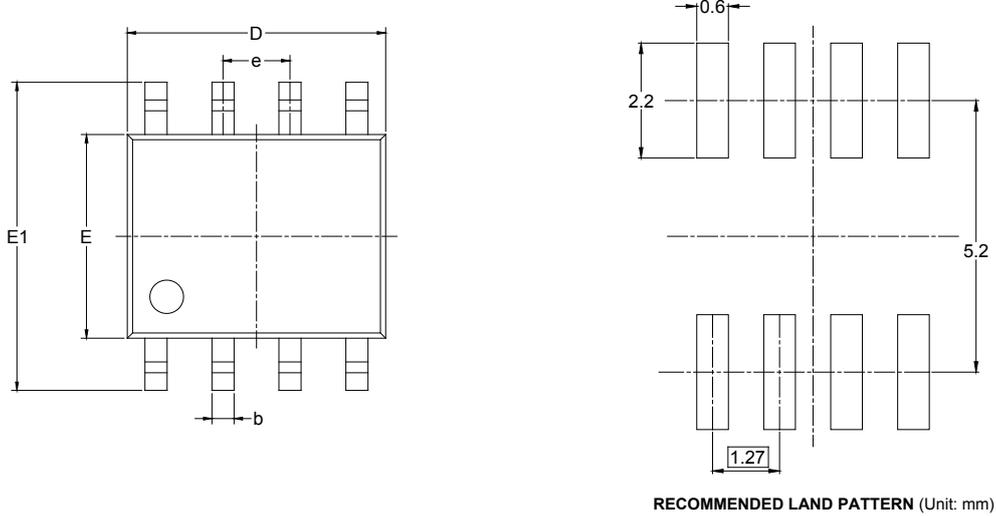
RECOMMENDED LAND PATTERN (Unit: mm)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
$\theta$	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

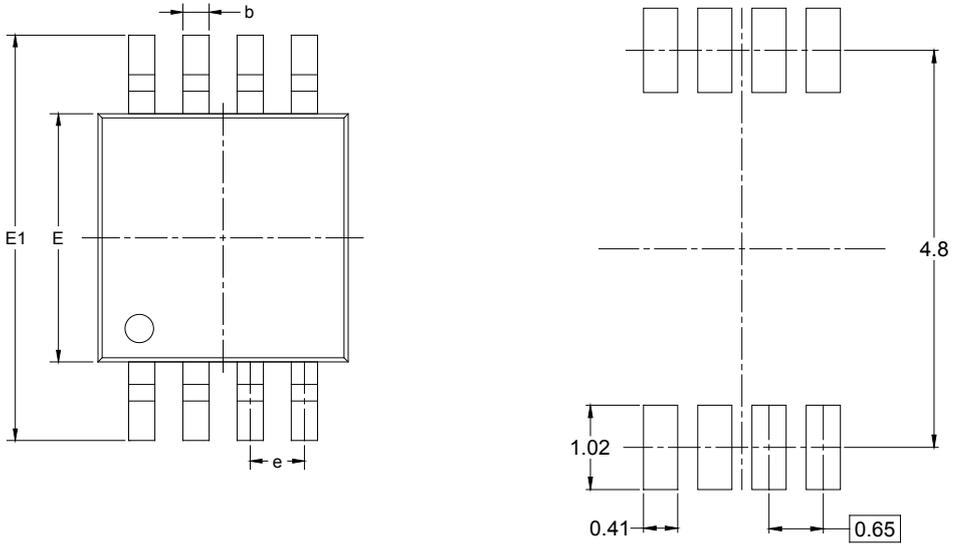
SOIC-8



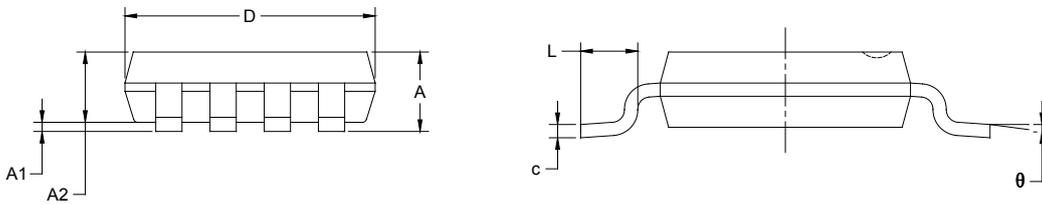
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

MSOP-8



RECOMMENDED LAND PATTERN (Unit: mm)

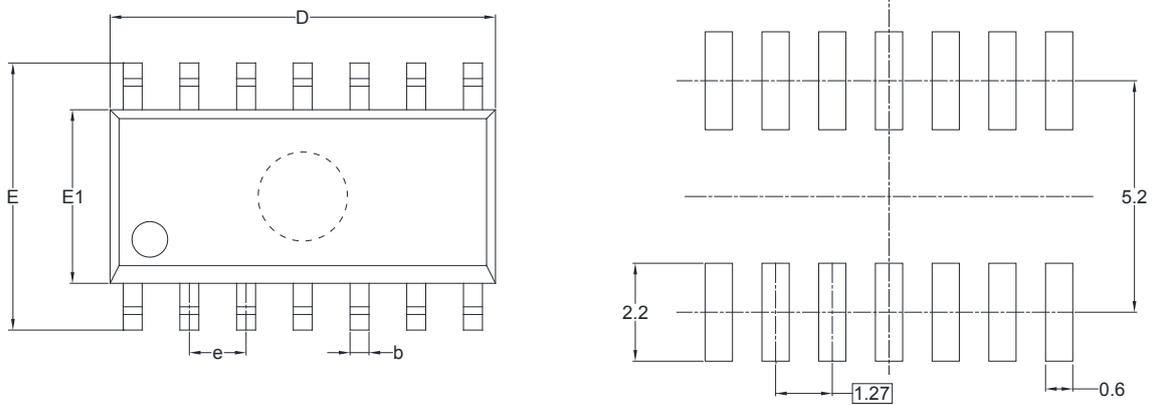


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.250	0.380	0.010	0.015
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.650 BSC		0.026 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

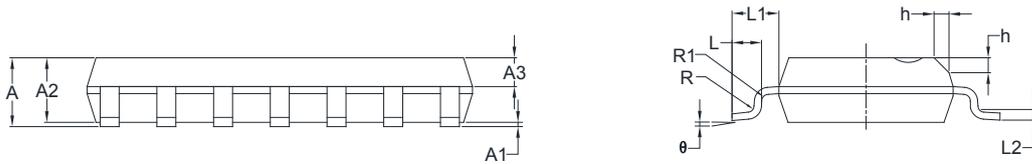
# PACKAGE INFORMATION

## PACKAGE OUTLINE DIMENSIONS

### SOIC-14



RECOMMENDED LAND PATTERN (Unit: mm)

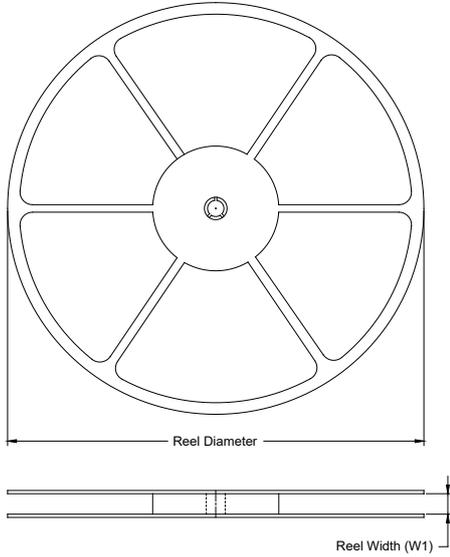


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.053	0.069
A1	0.10	0.25	0.004	0.010
A2	1.25	1.65	0.049	0.065
A3	0.55	0.75	0.022	0.030
b	0.36	0.49	0.014	0.019
D	8.53	8.73	0.336	0.344
E	5.80	6.20	0.228	0.244
E1	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
L	0.45	0.80	0.018	0.032
L1	1.04 REF		0.040 REF	
L2	0.25 BSC		0.01 BSC	
R	0.07		0.003	
R1	0.07		0.003	
h	0.30	0.50	0.012	0.020
θ	0°	8°	0°	8°

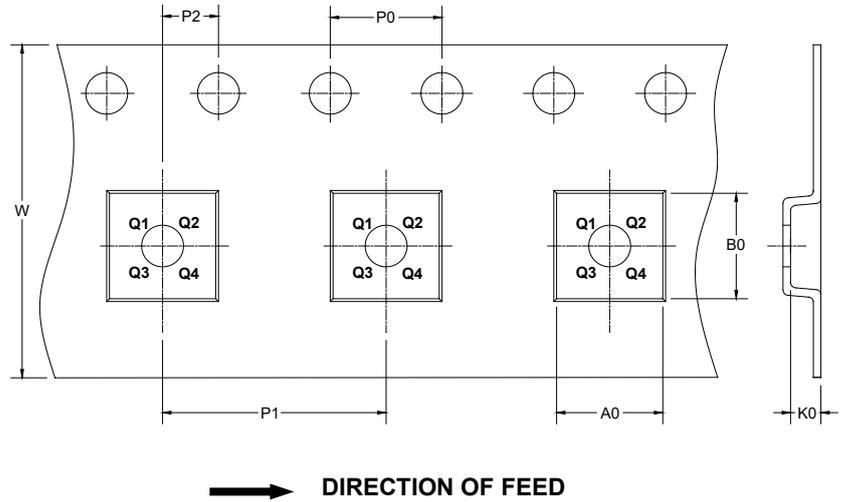
# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

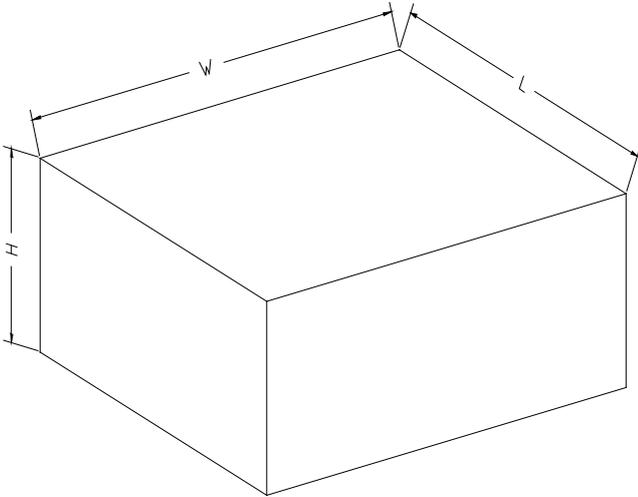
### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1
MSOP-8	13"	12.4	5.20	3.30	1.50	4.0	8.0	2.0	12.0	Q1
SOIC-14	13"	16.4	6.60	9.30	2.10	4.0	8.0	2.0	16.0	Q1

D00001

# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

DD0002